NSN 5961-01-294-1289

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-294-1289 **Inclosure Material:** Glass **Overall Length:** 0.179 inches **Terminal Length:** 1.102 inches **Overall Diameter:** 0.149 inches **Function For Which Designed:** General purpose **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method: Terminal Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 800.0 repetitive peak reverse voltage and 1.6 forward voltage, dc **Current Rating Per Characteristic:** 10.00 amperes forward current, average absolute **Maximum Operating Tempurature Per Measurement Point:** 165.0 degrees celsius junction **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life:

N/a		
Unit Of Measure:		
Demilitarization:		
No		
Fiig:		
A110a0		